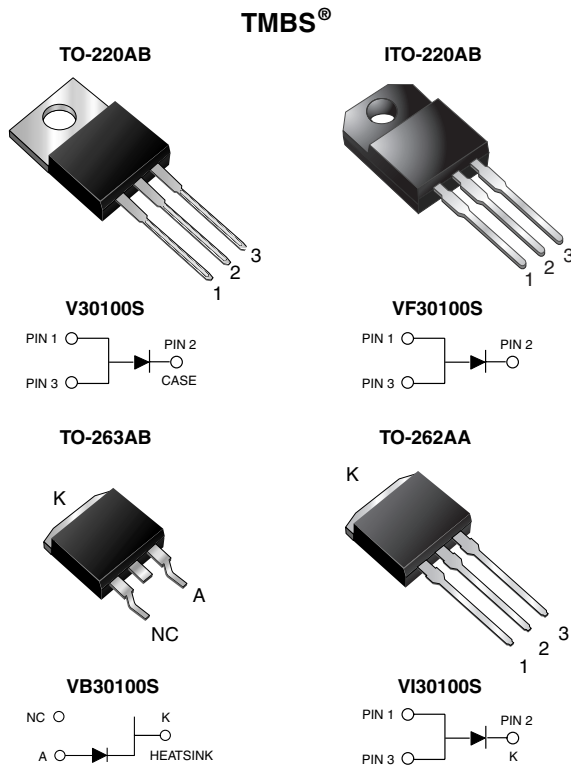


High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.39\text{ V}$ at $I_F = 5\text{ A}$



FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Low thermal resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 260 °C, 40 s (for TO-220AB, ITO-220AB, and TO-262AA package)
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



RoHS
COMPLIANT

TYPICAL APPLICATIONS

For use in high frequency inverters, switching power supplies, freewheeling diodes, OR-ing diode, dc-to-dc converters and reverse battery protection.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB and TO-262AA

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

PRIMARY CHARACTERISTICS

$I_{F(AV)}$	30 A
V_{RRM}	100 V
I_{FSM}	250 A
V_F at $I_F = 30\text{ A}$	0.69 V
T_J max.	150 °C

MAXIMUM RATINGS ($T_A = 25\text{ °C}$ unless otherwise noted)

PARAMETER	SYMBOL	V30100S	VF30100S	VB30100S	VI30100S	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	100				V
Maximum average forward rectified current (Fig. 1)	$I_{F(AV)}$	30				A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I_{FSM}	250				A
Isolation voltage (ITO-220AB only) From terminal to heatsink $t = 1\text{ min}$	V_{AC}	1500				V
Operating junction and storage temperature range	T_J, T_{STG}	- 40 to + 150				°C

ELECTRICAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Breakdown voltage	$I_R = 10\text{ mA}$	$T_A = 25\text{ }^\circ\text{C}$	V_{BR}	105 (minimum)	-	V
Instantaneous forward voltage ⁽¹⁾	$I_F = 5\text{ A}$ $I_F = 10\text{ A}$ $I_F = 30\text{ A}$	$T_A = 25\text{ }^\circ\text{C}$	V_F	0.47 0.55 0.80	- - 0.91	V
	$I_F = 5\text{ A}$ $I_F = 10\text{ A}$ $I_F = 30\text{ A}$	$T_A = 125\text{ }^\circ\text{C}$		0.39 0.49 0.69	- - 0.78	
Reverse current ⁽²⁾	$V_R = 70\text{ V}$	$T_A = 25\text{ }^\circ\text{C}$ $T_A = 125\text{ }^\circ\text{C}$	I_R	27 11	- -	μA mA
	$V_R = 100\text{ V}$	$T_A = 25\text{ }^\circ\text{C}$ $T_A = 125\text{ }^\circ\text{C}$		70 23	1000 45	μA mA

Notes:

(1) Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width $\leq 40\text{ ms}$

THERMAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)						
PARAMETER	SYMBOL	V30100S	VF30100S	VB30100S	VI30100S	UNIT
Typical thermal resistance	$R_{\theta JC}$	2.0	4.0	2.0	2.0	$^\circ\text{C/W}$

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-220AB	V30100S-E3/45	1.875	45	50/tube	Tube
ITO-220AB	VF30100S-E3/45	1.805	45	50/tube	Tube
TO-263AB	VB30100S-E3/4W	1.380	4W	50/tube	Tube
TO-263AB	VB30100S-E3/8W	1.380	8W	800/reel	Tape and reel
TO-262AA	VI30100S-E3/4W	1.455	4W	50/tube	Tube

RATINGS AND CHARACTERISTICS CURVES

($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)

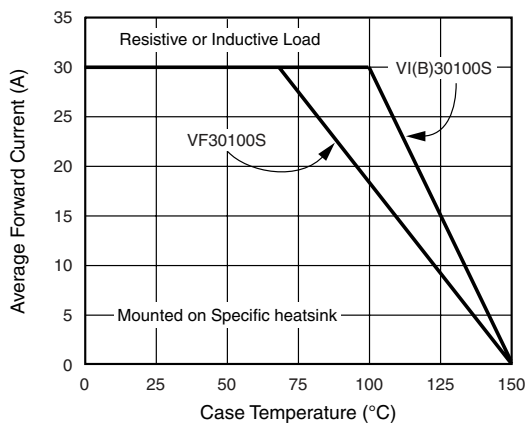


Figure 1. Forward Current Derating Curve

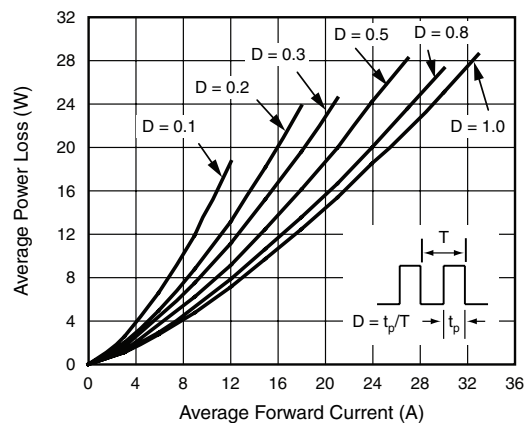


Figure 2. Forward Power Loss Characteristics

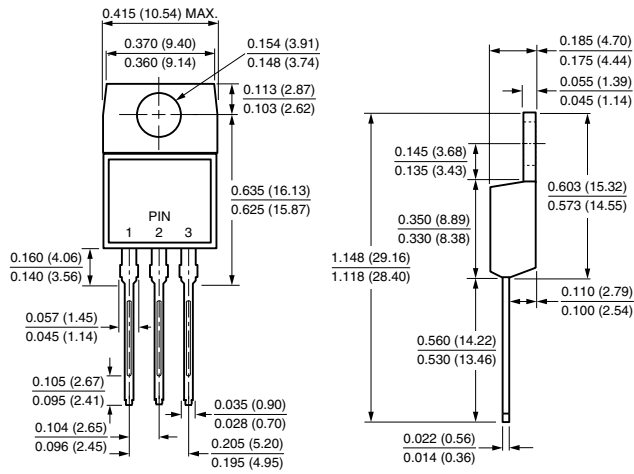
New Product V30100S, VF30100S, VB30100S & VI30100S



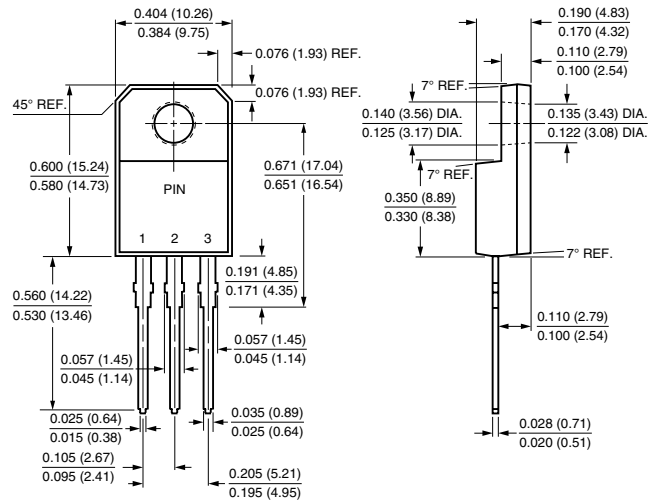
Vishay General Semiconductor

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

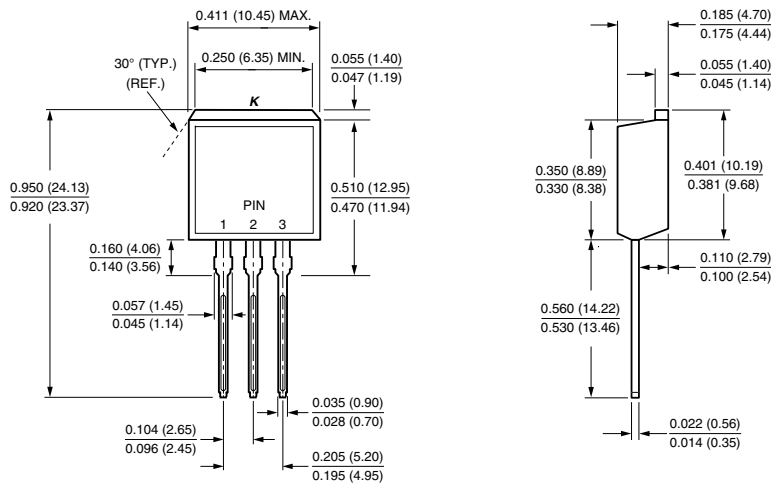
TO-220AB



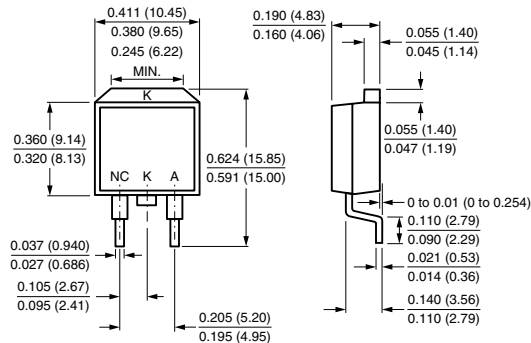
ITO-220AB



TO-262AA



TO-263AB



Mounting Pad Layout

